

# SN74CBTLV16800

## LOW-VOLTAGE 20-BIT FET BUS SWITCH WITH PRECHARGED OUTPUTS

SCDS045G – DECEMBER 1997 – REVISED MAY 2000

- **5-Ω Switch Connection Between Two Ports**
- **Isolation Under Power-Off Conditions**
- **B-Port Outputs Are Precharged by Bias Voltage to Minimize Signal Distortion During Live Insertion**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**
- **Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II**
- **Package Options Include Plastic Thin Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV), and Shrink Small-Outline (DL) Packages**

NOTE: For tape and reel order entry:  
The DGGR package is abbreviated to GR, and  
the DGVR package is abbreviated to VR.

### description

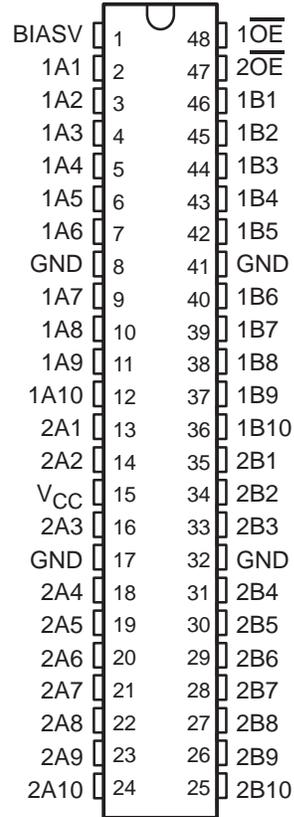
The SN74CBTLV16800 provides 20 bits of high-speed bus switching. The low on-state resistance of the switch allows connections to be made with minimal propagation delay. The device also precharges the B port to a user-selectable bias voltage (BIASV) to minimize live-insertion noise.

The device is organized as dual 10-bit bus switches with separate output-enable ( $\overline{OE}$ ) inputs. It can be used as two 10-bit bus switches or one 20-bit bus switch. When  $\overline{OE}$  is low, the associated 10-bit bus switch is on, and port A is connected to port B. When  $\overline{OE}$  is high, the switch is open, the high-impedance state exists between the two ports, and port B is precharged to BIASV through the equivalent of a 10-kΩ resistor.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74CBTLV16800 is characterized for operation from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

### DGG, DGV, OR DL PACKAGE (TOP VIEW)



**FUNCTION TABLE**  
(each 10-bit bus switch)

| INPUT<br>$\overline{OE}$ | FUNCTION                     |
|--------------------------|------------------------------|
| L                        | A port = B port              |
| H                        | A port = Z<br>B port = BIASV |



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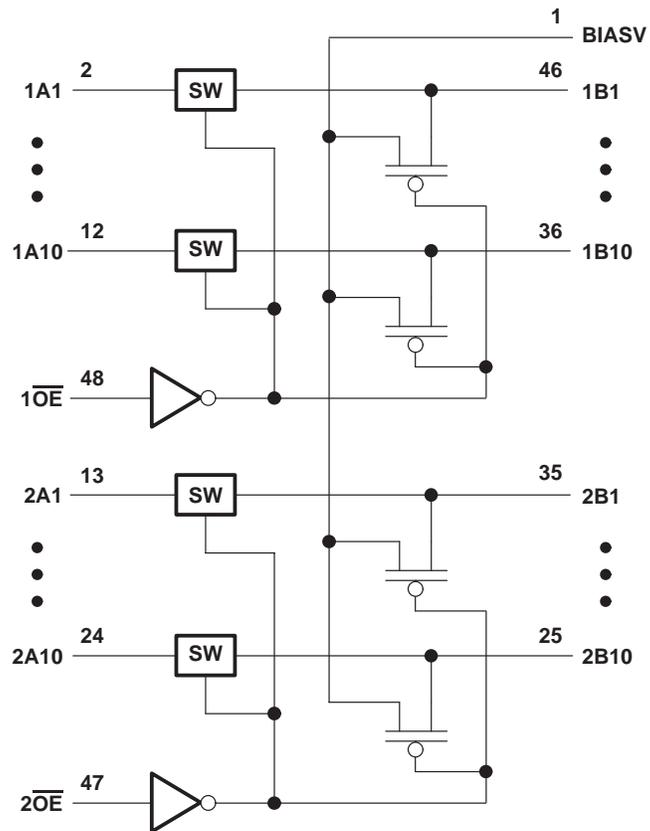
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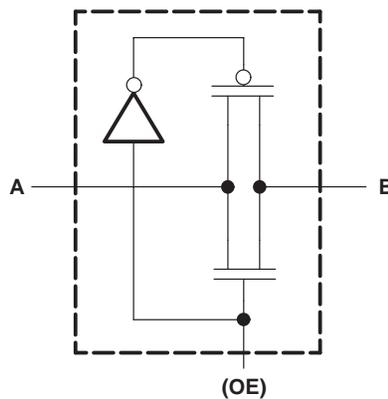
# SN74CBTLV16800 LOW-VOLTAGE 20-BIT FET BUS SWITCH WITH PRECHARGED OUTPUTS

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## logic diagram (positive logic)



## simplified schematic, each FET switch



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**LOW-VOLTAGE 20-BIT FET BUS SWITCH**  
**WITH PRECHARGED OUTPUTS**

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**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†**

|  |                 |
|--|-----------------|
| Supply voltage range, $V_{CC}$ .....                                     | -0.5 V to 4.6 V |
| Bias voltage range, BIASV .....  | -0.5 V to 4.6 V |
| Input voltage range, $V_I$ (see Note 1) .....                            | -0.5 V to 4.6 V |
| Continuous channel current .....   | 128 mA          |
| Input clamp current, $I_{IK}$ ( $V_I < 0$ ) .....                        | -50 mA          |
| Package thermal impedance, $\theta_{JA}$ (see Note 2): DGG package ..... | 70°C/W          |
| DGV package .....  | 58°C/W          |
| DL package .....   | 63°C/W          |
| Storage temperature range, $T_{stg}$ .....                               | -65°C to 150°C  |

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.  
2. The package thermal impedance is calculated in accordance with JESD 51.

**recommended operating conditions (see Note 3)**

|          |                                  | MIN  | MAX      | UNIT |
|----------|----------------------------------|--|----------|------|
| $V_{CC}$ | Supply voltage                   | 2.3  | 3.6      | V    |
| BIASV    | Bias voltage                     | 1.3  | $V_{CC}$ | V    |
| $V_{IH}$ | High-level control input voltage | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | 1.7      | V    |
|          |                                  | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | 2        |      |
| $V_{IL}$ | Low-level control input voltage  | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | 0.7      | V    |
|          |                                  | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | 0.8      |      |
| $T_A$    | Operating free-air temperature   | -40  | 85       | °C   |

NOTE 3: All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

| PARAMETER            | TEST CONDITIONS   |                            | MIN                         | TYP‡                            | MAX  | UNIT |    |
|----------------------|---|----------------------------|-----------------------------|---------------------------------|------|------|----|
| $V_{IK}$             | $V_{CC} = 3 \text{ V}$ ,                                      | $I_I = -18 \text{ mA}$     |                             |                                 | -1.2 | V    |    |
| $I_I$                | $V_{CC} = 3.6 \text{ V}$ ,                                    | $V_I = V_{CC}$ or GND      |                             |                                 | ±1   | µA   |    |
| $I_{off}$            | A port  | $V_{CC} = 0$ ,             | $V_I$ or $V_O = 0$ to 3.6 V |                                 | 10   | µA   |    |
| $I_O$                | $V_{CC} = 3 \text{ V}$ ,                                      | BIASV = 2.4 V,             | $V_O = 0$ ,                 | $\overline{OE} = V_{CC}$        | 0.25 | mA   |    |
| $I_{CC}$             | $V_{CC} = 3.6 \text{ V}$ ,                                    | $I_O = 0$ ,                | $V_I = V_{CC}$ or GND       |                                 | 10   | µA   |    |
| $\Delta I_{CC}^{\S}$ | Control inputs  | $V_{CC} = 3.6 \text{ V}$ , | One input at 3 V,           | Other inputs at $V_{CC}$ or GND |      | 300  | µA |
| $C_i$                | Control inputs  | $V_I = 3 \text{ V}$ or 0   |                             | 4.5                             |      | pF   |    |
| $C_{io(OFF)}$        |   | $V_O = 3 \text{ V}$ or 0,  | Switch off,                 | BIASV = Open                    |      | 6.5  | pF |
| $r_{on}^{\parallel}$ | $V_{CC} = 2.3 \text{ V}$ ,<br>TYP at $V_{CC} = 2.5 \text{ V}$ | $V_I = 0$                  | $I_I = 64 \text{ mA}$       | 5                               | 9    | Ω    |    |
|                      |   |                            | $I_I = 24 \text{ mA}$       | 5                               | 9    |      |    |
|                      |   | $V_I = 1.7 \text{ V}$ ,    | $I_I = 15 \text{ mA}$       | 25                              | 35   |      |    |
|                      | $V_{CC} = 3 \text{ V}$  | $V_I = 0$                  | $I_I = 64 \text{ mA}$       | 5                               | 7    |      |    |
|                      |   |                            | $I_I = 24 \text{ mA}$       | 5                               | 7    |      |    |
|                      |   | $V_I = 2.4 \text{ V}$ ,    | $I_I = 15 \text{ mA}$       | 8                               | 15   |      |    |

‡ All typical values are at  $V_{CC} = 3.3 \text{ V}$  (unless otherwise noted),  $T_A = 25^\circ\text{C}$ .

§ This is the increase in supply current for each input that is at the specified voltage level rather than  $V_{CC}$  or GND.

∥ Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.



# SN74CBTLV16800

## LOW-VOLTAGE 20-BIT FET BUS SWITCH

### WITH PRECHARGED OUTPUTS

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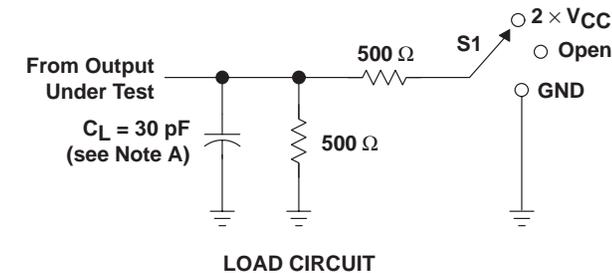
switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 and 2)

| PARAMETER        | TEST CONDITIONS | FROM (INPUT)           | TO (OUTPUT) | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ |     | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |     | UNIT |
|------------------|-----------------|------------------------|-------------|--|-----|--|-----|------|
|                  |                 |                        |             | MIN  | MAX | MIN  | MAX |      |
| $t_{pd}^\dagger$ |                 | A or B                 | B or A      | 0.35                                       |     | 0.25                                       |     | ns   |
| $t_{pZH}$        | BIASV = GND     | $\overline{\text{OE}}$ | A or B      | 2.9  | 7.7 | 2.2  | 5.5 | ns   |
| $t_{pZL}$        | BIASV = 3 V     |                        |             | 2.8  | 6.4 | 2.1  | 5.3 |      |
| $t_{pHZ}$        | BIASV = GND     | $\overline{\text{OE}}$ | A or B      | 1.4  | 6.8 | 2.6  | 7.6 | ns   |
| $t_{pLZ}$        | BIASV = 3 V     |                        |             | 1.3  | 4.2 | 1.5  | 5.1 |      |

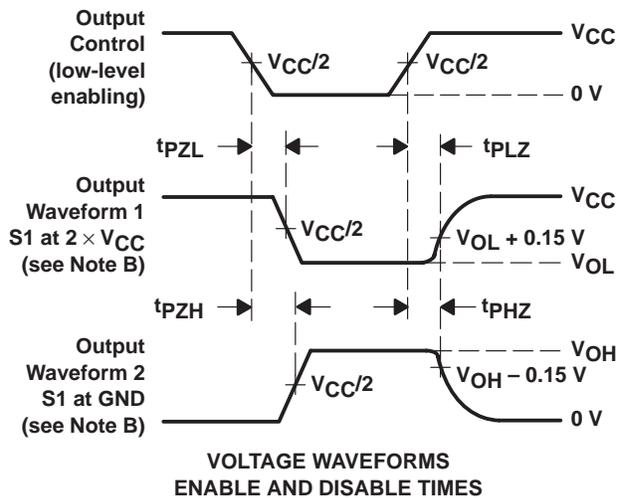
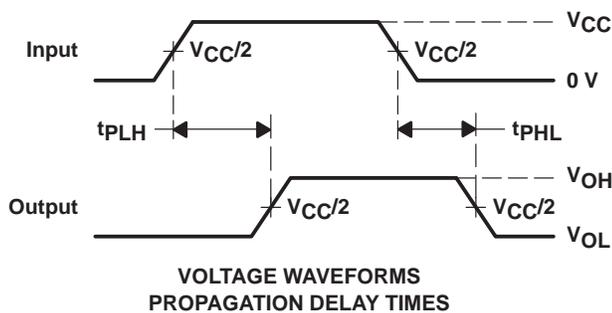
† The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

### PARAMETER MEASUREMENT INFORMATION

$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



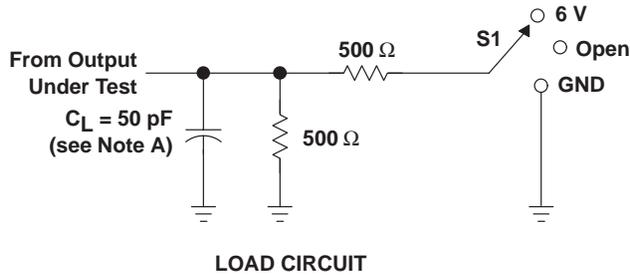
| TEST              | S1                |
|-------------------|-------------------|
| $t_{pd}$          | Open              |
| $t_{pLZ}/t_{pZL}$ | 2 $\times V_{CC}$ |
| $t_{pHZ}/t_{pZH}$ | GND               |



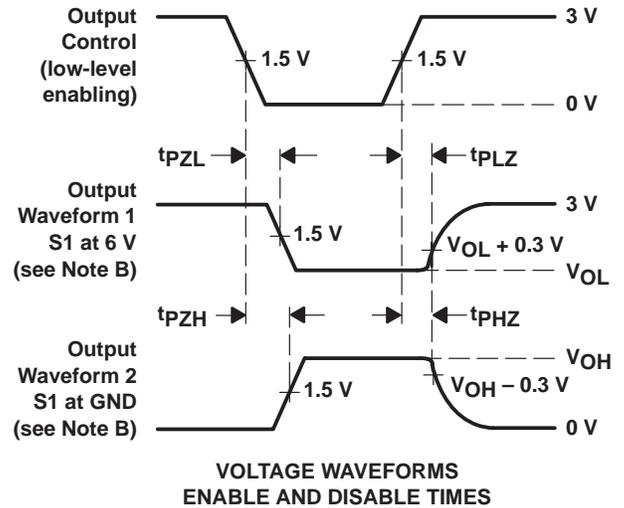
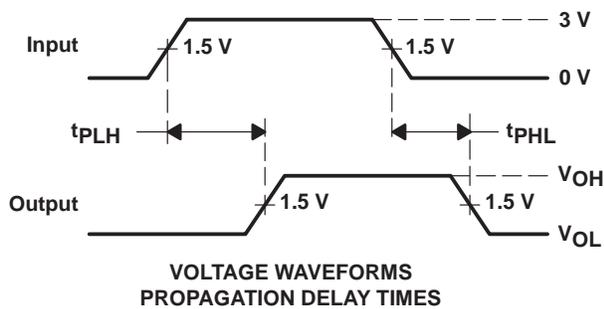
- NOTES:
- $C_L$  includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r \leq 2 \text{ ns}$ ,  $t_f \leq 2 \text{ ns}$ .
  - The outputs are measured one at a time with one transition per measurement.
  - $t_{pLH}$  and  $t_{pHL}$  are the same as  $t_{pd}$ .

Figure 1. Load Circuit and Voltage Waveforms

**PARAMETER MEASUREMENT INFORMATION**  
 $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$



| TEST              | S1   |
|-------------------|------|
| $t_{pd}$          | Open |
| $t_{PLZ}/t_{PZL}$ | 6 V  |
| $t_{PHZ}/t_{PZH}$ | GND  |



- NOTES:
- A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\text{ MHz}$ ,  $Z_O = 50\ \Omega$ ,  $t_r \leq 2.5\text{ ns}$ ,  $t_f \leq 2.5\text{ ns}$ .
  - D. The outputs are measured one at a time with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

**Figure 2. Load Circuit and Voltage Waveforms**

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